



## DEPARTMENT OF PHYSICS AND NANOTECHNOLOGY SRM INSTITUTE OF SCIENCE AND TECHNOLOGY

**18PYB103J – Semiconduuctor Physics** 

# Optical Transitions Using Fermi's Golden Rule





#### Introduction

Fermi's golden rule is a simple expression for the transition probabilities between states of a quantum system, which are subjected to a perturbation. It is used for a large variety of physical systems covering, e.g., nuclear reactions, optical transitions, or scattering of electrons in solids.

Consider a semiconductor illuminated by electromagnetic radiations (light). The interaction between photons and the electrons in the semiconductor can be described by the Hamiltonian operator.

$$\vec{H} = \frac{1}{2m_0} (\vec{p} - e\vec{A})^2 + \vec{V}(r)$$

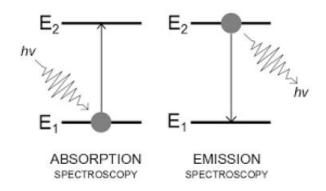
Where,

m  $_0$  is the free electron mass,  $\vec{A}$  is the vector potential accounting part of electromagnetic field.

$$\overrightarrow{V}(r)$$
 is the periodic potential and  $e = -|e|$ 







Using the time dependent perturbation theory, the transition rate for the absorption of a photon can be derived, assuming an electron is initially at state  $E_1$  is given by Fermi's Golden rule

$$W_{abs} = \frac{2\pi}{\hbar} |\langle b|H'(r)|a \rangle|^2 \delta (E_b - E_a - \hbar \omega)$$

Where  $E_b > E_a$  is assumed.

The total upward transition rate per unit volume

Where  $E_b > E_a$  has been assumed. The total upward transition rate per unit volume(S<sup>-1</sup>, cm<sup>-3</sup>) in the crystal taking into account the probability that state a is occupied and state b is empty is

$$R_{a-b} = \frac{2}{v} \sum_{K_a} \sum_{K_b} \frac{2\pi}{\hbar} \left| H'_{ba} \right|^2 \delta \left( E_b - E_a - \hbar \omega \right) f_a \left( 1 - f_b \right)$$





Where we sum over the initial and final states and assume that the Fermi-Dirac distribution  $f_a$  is the probability that the state a is occupied. A similar expression holds for  $f_b$  with  $E_a$  replaced by  $E_b$ , and  $(1 - f_b)$  is probability that the state b is empty. The prefactor 2 takes into account the sum over spins, and the matrix element  $H'_{ba}$  is given by

$$H'_{ba} = |\langle b|H'(r)|a \rangle|^2 = \int \psi^*(r)H'(r)\psi_a(r)d^3r$$

Similarly, The transition rate for the emission of a photon (fig.2) if an electron is initially at state b is.

$$W_{\text{ems}} = \frac{2\pi}{\hbar} \left| \langle a | H'^{+}(r) | b \rangle \right|^{2} \delta \left( E_{a} - E_{b} + \hbar \omega \right)$$

The downward transition rate per unit volume (S<sup>-1</sup> cm<sup>-3</sup>) is

$$R_{b-a} = \frac{2}{V} \sum_{K_a} \sum_{K_b} \frac{2\pi}{\hbar} |H'^{+}_{ab}|^2 \delta (E_a - E_b + \hbar \omega) f_b (1 - f_a)$$





Using the even property of the delta function,  $\delta(-x) = \delta(x)$  and  $|H'_{ba}| = |H'_{ab}|$ .

The net upward transition rate per unit volume can be written as,

$$R = R_{a \to b} - R_{b \to a}$$

$$R = \frac{2}{V} \sum_{K_a} \sum_{K_b} \frac{2\pi}{\hbar} \left| H'_{ba} \right|^2 \delta \left( E_b - E_a - \hbar \omega \right) (f_a - f_b)$$

An Optical absorption coefficient

The absorption coefficient  $\alpha_0$  ( $\frac{1}{cm}$ ) in the crystal is the fraction of photons absorbed per unit distance

$$\alpha_0 = \frac{Number\ or\ Photons\ absorbed\ per\ second\ per\ unit\ volume}{Number\ of\ injected\ photons\ per\ second\ per\ unit\ area}$$





The injected number of photons per second per unit area of the optical intensity  $\rho$  (W/Cm<sup>2</sup>) divided by the energy of a photon ( $\hbar\omega$ ). Therefore,

$$\alpha (\hbar \omega) = \frac{R}{\frac{p}{\hbar \omega}} = \frac{\hbar \omega R}{(\frac{n_r C \varepsilon_0 \omega^2 A_0^2}{2})}$$

Where, R is the net upward transition rate per unit volume

 $\omega - \frac{2\pi}{\lambda}$ , wave number / angular velocity

C- Velocity of light

 $n_r$  – Refractive index of the medium.

A – Vector potential for electromagnetic field.

 $\varepsilon_0$ - Permittivity of the free space.





### Thank you